NSN 5961-01-313-6413

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-313-6413 **Inclosure Material:** Metal **Overall Length:** 1.125 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.551 inches and 0.557 inches Thready Qty Per Inch (tpi): 28 **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 660.0 nonrepetitive peak reverse voltage, peak total value, gate terminal open-circuited and 400.0 repetitive peak reverse voltage, peak total value, gate terminal open-circuited and 1.1 gate trigger voltage, dc **Current Rating Per Characteristic:** 35.00 amperes drain current horsepower metric and 22.00 amperes drain current universal and 25.00 milliamperes drain current preset **Power Rating Per Characteristic:** 40.0 watts any acceptable blank and 0.5 watts any acceptable universal **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli